Spintronic single qubit gate based on a quantum ring with spin-orbit interaction

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In a quantum ring connected with two external leads the spin properties of an incoming electron are modified by the spin-orbit interaction resulting in a transformation of the qubit state carried by the spin. The ring acts as a one qubit spintronic quantum gate whose properties can be varied by tuning the Rashba parameter of the spin-orbit interaction, by changing the relative position of the junctions, as well as by the size of the ring. We show that a large class of unitary transformations can be attained with already one ring – or a few rings in series – including the important cases of the Z, X, and Hadamard gates. By choosing appropriate parameters the spin transformations can be made unitary, which corresponds to lossless gates.

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The electron spin degree of freedom is one of the prospective carriers [1, 2] of qubits, the fundamental units in quantum information processing. In order to implement quantum operations on electron spins, appropriate gates are necessary that operate on this type of qubits. We note that in the present context the word 'gate' stands for an elementary logical operation [3]. In this paper we show that a one dimensional ring [4] connected with two external leads made of a semiconductor structure [5], such as InGaAs in which Rashba-type [6] spin-orbit interaction is the dominant spin-flipping mechanism, can render such a gate. Conductance properties of this kind of rings have been discussed earlier in the case of diametrically connected leads [7, 8, 9].

By taking here a new point of view, we focus explicitly on the spin transformation characteristics of this device, and show that those can be appropriately controlled by varying its geometrical and physical parameters in the experimentally feasible range [7, 8]. We shall determine the effects of changing the radius and the relative positions of the junctions, as well as the influence of varying the strength of the spin-orbit interaction via an external electric field. The conditions under which the incoming and transmitted spinors are connected unitarily will be determined, leading in principle, to a lossless single qubit gate. By connecting a few such rings in an appropriate manner, one can achieve practically all the important one qubit gates [3].

We consider a ring of radius a in the $x-y$ plane and assume a tunable static electric field [7] in the z direction characterized by the parameter α. Then the spin dependent Hamiltonian [9, 10] of a charged particle of effective mass m^* is

$$H = \hbar\Omega\left[\left(-i\frac{\partial}{\partial\varphi} + \frac{\omega}{2\Omega}(\sigma_x\cos\varphi + \sigma_y\sin\varphi)\right)^2 - \frac{\omega^2}{4\Omega^2}\right], \tag{1}$$

where φ is the azimuthal angle of a point on the ring, $\hbar\Omega = \hbar^2/2m^*a^2$ is the parameter characterizing the kinetic energy of the charge and $\omega = \alpha/\hbar a$ is the frequency associated with the spin-orbit interaction. Apart from constants, the Hamiltonian (1) is the square of the sum of the z component of the orbital angular momentum operator $L_z = -i\frac{\partial}{\partial\varphi}$, and of $\frac{\omega}{\Omega}S_r$, where $S_r = \sigma_r/2$ is the radial component of the spin (both measured in units of $\hbar$). H commutes in a nontrivial way with $K = L_z + S_z$, the z component of the total angular momentum. H also commutes with $S_{\theta\varphi} = S_x\sin\theta\cos\varphi + S_y\sin\theta\sin\varphi + S_z\cos\theta$, the spin component in the direction determined by the angles θ, and φ, where θ is given by

$$\tan\theta = -\omega/\Omega. \tag{2}$$

One easily can prove that the commutator $[K, S_{\theta\varphi}] = 0$ and therefore, we may look for simultaneous eigenstates of H, K and $S_{\theta\varphi}$. In the $|+\rangle$, $|-\rangle$ eigenbasis of S_z one finds these in the form:

$$\psi(\kappa,\varphi) = e^{i\kappa\varphi}\begin{pmatrix} e^{-i\varphi/2}u(\kappa) \\ e^{i\varphi/2}v(\kappa)\end{pmatrix} \tag{3}$$

obeying:

$$K\psi(\kappa,\varphi) = \kappa\psi(\kappa,\varphi) \tag{4a}$$

$$S_{\theta\varphi}\psi(\kappa,\varphi) = s(\kappa)\psi(\kappa,\varphi), \quad s(\kappa) = \pm 1/2 \tag{4b}$$

and the energy eigenvalues are

$$E = \hbar\Omega\left[\kappa^2 - \mu\kappa w + 1/4\right], \quad \mu = \pm 1, \tag{5}$$

with $w = \sqrt{1 + (\omega^2/\Omega^2)}$. In a closed ring $\kappa \pm 1/2$ must be integer, while if one considers leads connected to the ring, there is no such restriction: the energy is a continuous variable, and then the possible values of κ are the solutions of Eq. (5), which can be written as:

$$\kappa_j^\mu = \mu(w/2 + (-1)^j q), \qquad j = 1, 2, \quad \mu = \pm 1, \tag{6}$$

where $q = \sqrt{(\omega/2\Omega)^2 + E/\hbar\Omega}$. The energy eigenvalues are four fold degenerate: $j = 1, 2$ correspond to two distinct values of $\left|\kappa_j^\mu\right|$, while the additional degeneracy at a

given j is resolved by the sign of κ_j^μ. The components of the eigenvectors in (3) are related as:

$$\frac{v(\kappa_j^\mu)}{u(\kappa_j^\mu)} = (\tan\theta/2)_\mu = \frac{\Omega}{\omega}\left(1-\mu w\right). \tag{7}$$

The two possible eigenvalues in Eq. (4b) are $s(\kappa_j^\mu) = -\mu/2$, accordingly the eigenstates for a given energy can be classified by giving the absolute value of $\kappa_j^\pm$, together with the sign of the eigenvalue of $S_{\theta\varphi}$.

The stationary states of the problem: ring plus leads, can be determined by fitting the solutions obtained in the different domains. Using local coordinates as shown in Fig. 1, the incoming wave, $\Psi_I(x)$, and the outgoing wave $\Psi_{II}(x')$ are built up as linear combinations of spinors with spatial dependence e^{ikx} etc. corresponding to $E = \hbar^2k^2/2m^*$:

$$\Psi_I(x) = \begin{pmatrix} f_1 \\ f_2 \end{pmatrix} e^{ikx} + \begin{pmatrix} r_1 \\ r_2 \end{pmatrix} e^{-ikx}, \quad \Psi_{II}(x') = \begin{pmatrix} t_1 \\ t_2 \end{pmatrix} e^{ikx'}. \tag{8}$$

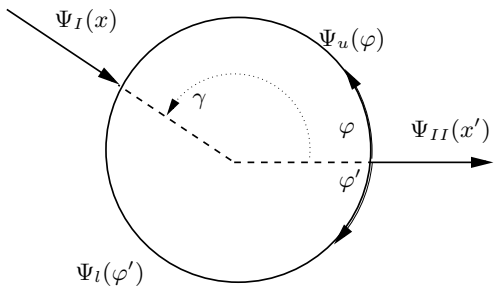

FIG. 1: The geometry of the device and the relevant wave functions in the different domains.

The wave functions belonging to the same energy can be written as linear combinations of the corresponding four eigenspinors in the upper and lower arms of the ring as:

$$\Psi_u(\varphi) = \sum_{\substack{j=1,2\\ \mu=\pm}} a_j^\mu \psi(\kappa_j^\mu, \varphi); \quad \Psi_l(\varphi') = \sum_{\substack{j=1,2\\ \mu=\pm}} b_j^\mu \psi(\kappa_j^\mu, -\varphi'), \tag{9}$$

respectively. According to Fig. 1 the incoming wave at $x = 0$ is fitted to Ψ_u at $\varphi = \gamma$ and to Ψ_l at $\varphi' = 2\pi - \gamma$, while the outgoing wave at $x' = 0$ is fitted to Ψ_u and Ψ_l at $\varphi = \varphi' = 0$. One has to require the continuity of the wave functions, as well as a vanishing spin current density at the two junctions [9, 11, 12]. The resulting set of linear equations leads to a relation between the expansion coefficients in the different domains. The detailed procedure for the case $\gamma = \pi$ was described in Ref. 9 using the eigenbasis of $S_{\theta\varphi}$ at both junctions. As we will show, the more general geometry shown in Fig. 1. allows a significantly wider class of spin transformations to be described now in the fixed S_z basis, which is more suitable to discuss the qubit operations. We focus here on the transmission properties of the ring, and obtain in the $|+\rangle$, $|-\rangle$ basis:

$$\begin{pmatrix} t_1 \\ t_2 \end{pmatrix} = T \begin{pmatrix} f_1 \\ f_2 \end{pmatrix} = \begin{pmatrix} T_{11} & T_{12} \\ T_{21} & T_{22} \end{pmatrix} \begin{pmatrix} f_1 \\ f_2 \end{pmatrix}, \tag{10}$$

with

$$T = |T_\gamma|\, e^{i\delta_0/2} e^{-i\gamma/2} U, \tag{11}$$

where the matrix elements of U are $u_{11} = u_{22}^* = (e^{i\delta/2}\sin^2\frac{\theta}{2} + e^{-i\delta/2}\cos^2\frac{\theta}{2})e^{i\gamma/2}$, $u_{12} = -u_{21}^* = i\sin\frac{\delta}{2}\sin\theta e^{-i\gamma/2}$. $|T_\gamma|$ and the phases δ_0 and δ are obtained from

$$|T_\gamma|\, e^{i\delta_\pm} = \frac{4ikaq(\sin q(2\pi-\gamma) + e^{i\Phi_\pm}\sin q\gamma)e^{-i\gamma\Phi_\pm/2\pi}}{k^2a^2\left\{\cos 2q(\pi-\gamma) - \cos 2q\pi\right\} + 4q^2\left\{\cos\Phi - \cos 2q\pi\right\} + 4ikaq\sin 2q\pi}, \tag{12}$$

$$\delta_0 = \delta_+ + \delta_-, \qquad \delta = \delta_+ - \delta_- = 2\arctan\frac{\sin w\gamma\sin q(2\pi-\gamma) + \sin w(2\pi-\gamma)\sin q\gamma}{\cos w\gamma\sin q(2\pi-\gamma) - \cos w(2\pi-\gamma)\sin q\gamma}, \tag{13}$$

where $\cos\Phi_+ = \cos\Phi_- \equiv \cos\Phi$, with $\Phi_\pm = \pi(-1\pm w)$, the Aharonov-Casher phases [13] for the corresponding spin directions.

The important fact is that U is a unitary, unimodular matrix. It is this unitary part that performs a nontrivial spin transformation in the qubit space. In Eq. (11) $|T_\gamma|$ is a non-negative constant with $|T_\gamma| \le 1$, which can be considered as the efficiency of the gate. Therefore, one has in general $|t_1|^2 + |t_2|^2 \le 1$, nevertheless the transmitted amplitudes can be renormalized, and their absolute value squared give the probabilities of having the corresponding spin direction, if the particle is assumed to be transmitted at all. In certain cases, to be discussed below, we find, however, that T is unitary: $|T_\gamma| = 1$. We shall turn now to analyze the transformation properties of this device in more detail.

If the incoming and outgoing leads are connected to the ring diametrically, then $\gamma = \pi$, and as seen from (13) also $\delta = \pi$ independently from the energy. The transmission matrix then takes the form :

$$T = |T_\pi|\, e^{i(\delta_0+\pi)/2} \begin{pmatrix} \cos\theta & -\sin\theta \\ \sin\theta & \cos\theta \end{pmatrix} = |T_\pi|\, e^{i(\delta_0+\pi)/2} U, \tag{14}$$

with

$$|T_\pi| e^{i\delta_0/2} \;=\; \frac{8ikaq\sin(\pi q)\cos(\Phi/2)}{k^2a^2(1-\cos 2q\pi) + 4q^2(\cos\Phi - \cos 2q\pi) + 4ikaq\sin 2q\pi}. \tag{15}$$

The unitary part U of the transformation given by Eq. (14) is independent of the wave vector k, and it rotates the spin around the y axis [3] by an angle 2θ. By changing the strength of the spin-orbit interaction [7] $\omega = \alpha/\hbar a$, according to Eq.(2) the values of $|\theta|$ can be varied from 0 up to $0.8(\pi/2)$. Fig. 2 shows the gate efficiency $|T_\pi|$ as a function of $|\theta|$ and of ka around $k_F a = 20.4$, corresponding to a ring of radius $0.25\mu m$ and a Fermi energy 11.13 meV of InGaAs. One sees also that for several values of ka and θ the transformation is strictly unitary, with $|T_\pi| = 1$. If one couples such unitary devices in series, then obviously the resulting transformation will be the product of the corresponding unitary matrices, and will be unitary again.

In the language of quantum informatics [3], the transformation (14) above, represents a rather general single qubit gate, and it shows that in principle a continuous set of spin rotations can be achieved with already a single diametrically connected ring. This can be further extended by coupling two or more such rings in series. A transformation of the form (14) with $\theta = \pi/4$ is essentially a so called Hadamard gate [3], which plays a distinguished role in quantum algorithms, while two such gates in series results in an X gate or quantum NOT gate. Strictly speaking in both cases one has to introduce an additional relative phase between the components, in order to have the correct determinant (-1) of the transformations [3]. This is possible with $\gamma \neq \pi$ to be discussed below.

In the case of arbitrary γ other types of transformations can be realized. An important particular case is when $\delta = 0$, which can be achieved by tuning the voltage, α and thereby ω/Ω. Then one has:

$$T_\gamma(\delta = 0) = |T_\gamma| e^{i\delta_0/2} \begin{pmatrix} 1 & 0 \\ 0 & e^{-i\gamma} \end{pmatrix}, \tag{16}$$

and the unitary part of the transformation is a phase gate [3], where the phase difference introduced between spin up and spin down is just the geometrical angle γ (Fig. 1). Fig. 3 shows the curves along which such phase gates can be realized ($\delta = 0$ in Eq. (13)) depending on the values of ka and ω/Ω. The dots on the curves mark the points where $|T_\gamma| = 1$, and thus the transformation is unitary. In Fig. 4 we show the gate efficiency of a phase gate ($\delta = 0$) for the special value $\gamma = \pi/2$ as function of α and ka.

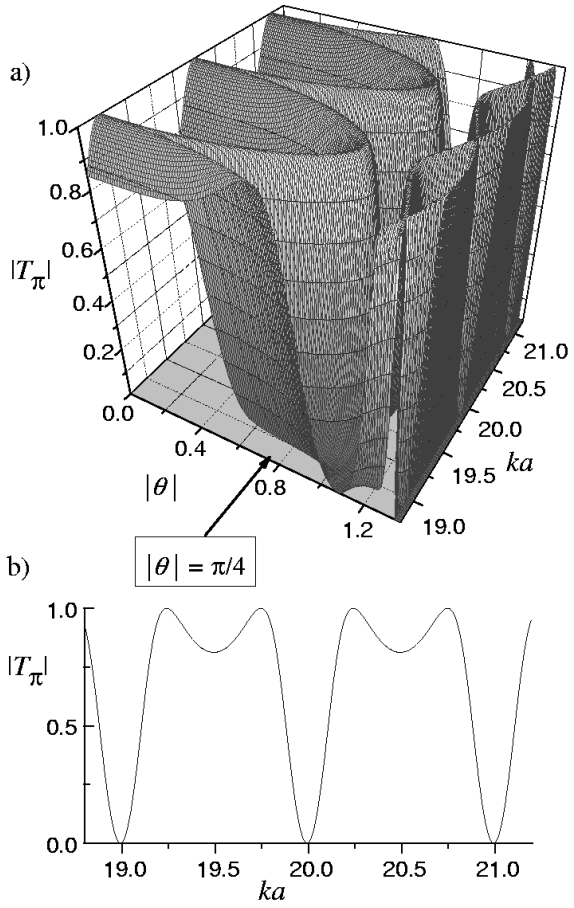

FIG. 2: (a) Efficiency $|T_\pi|$ of the quantum gate with $\gamma = \pi$ as a function of the modulus of the half rotation angle $\theta = -\arctan\omega/\Omega$ and ka. The maximal value of $|\theta|$ corresponds to $\omega/\Omega = 3.5$. (b) Cross section of the surface at $|\theta| = \pi/4$, where the transformation is essentially an Hadamard gate.

We note that in principle a number of other gates can be constructed by coupling several of those rings. This can be realized with parameters corresponding to unitary gates, so that the product of the corresponding spin rotations result again in a unitary transformation. For instance, two rings both with $\gamma = \pi/2$ in Eq. (16) is a Z gate [3]. If such a gate is coupled to a diametric ring associated to Eq. (14) with $\theta = \pi/4$, one obtains exactly an Hadamard gate. Similarly, two rings with $\gamma = \pi/2$, plus two of the type corresponding to Eq. (14) with $\theta = \pi/4$, yields a NOT gate with the correct phase.

In conclusion, we have shown that a quantum ring with Rashba type spin-orbit interaction can serve as a one qubit quantum gate for electron spins. The spin transformation properties of the gates can be extended by cou-

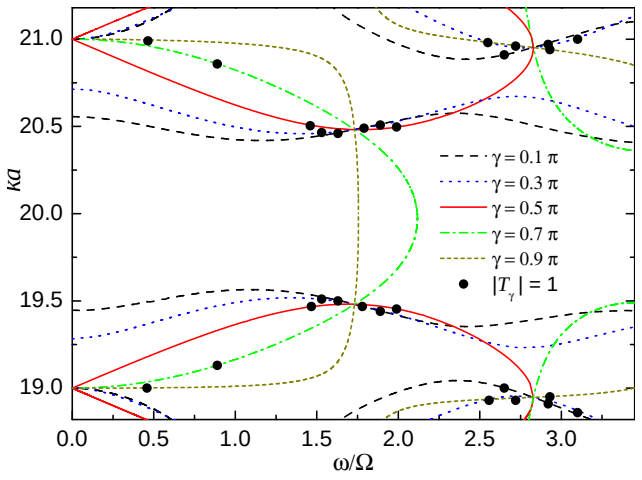

FIG. 3: Lines along which the ring acts as a γ phase gate. Points on the curves show where the gates are lossless i.e. $|T_\gamma| = 1$

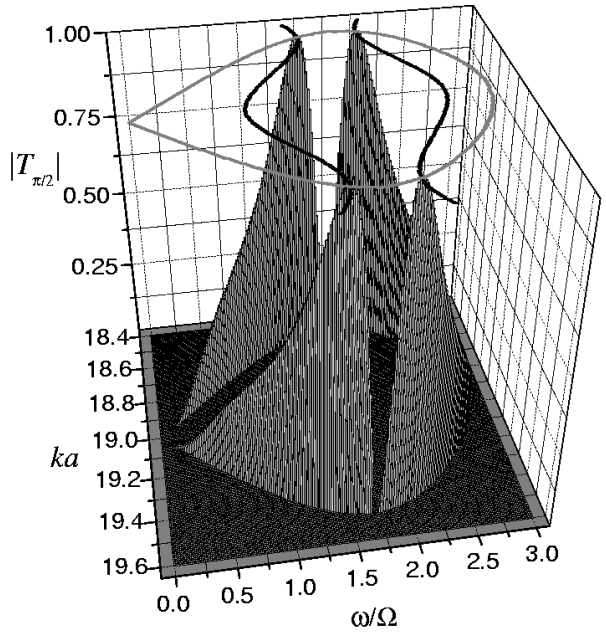

FIG. 4: Efficiency of a $\pi/2$ phase gate. Along the gray curve on the top ($ka - \omega/\Omega$) plane the ring acts as a $\pi/2$ gate. The black lines on the same plane show where the efficiency $|T_{\pi/2}|$ equals unity, thus at the crossing points of the black and gray lines this phase gate is unitary.

pling such rings in series. Different types of gates can be realized by tuning the electric field strength and changing the geometric position of the junctions connected to the ring, as well as by fabricating rings with different sizes. The considered parameters are within the experimentally feasible range [7, 8, 14]. In a ring of radius $a = 0.25\mu m$ and for InGaAs ($m^* = 0.023m$), α can be varied up to 2.0×10^{-11} eVm [7], which corresponds to $\theta = 0.8(\pi/2)$.

We note that similar rings in the presence of an external magnetic field can be used for spin filtering [9]. This points to the possibility to integrate gates and filters that can serve as elementary building blocks of a quantum network based on spin sensitive devices [15, 16, 17, 18].

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